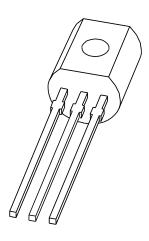
### DISCRETE SEMICONDUCTORS

## DATA SHEET



# **BC517**NPN Darlington transistor

Product specification Supersedes data of September 1994 File under Discrete Semiconductors, SC04 1997 Apr 23





## **NPN** Darlington transistor

**BC517** 

#### **FEATURES**

- High current (max. 500 mA)
- Low voltage (max. 30 V)
- Very high DC current gain (min. 30000).

#### **APPLICATIONS**

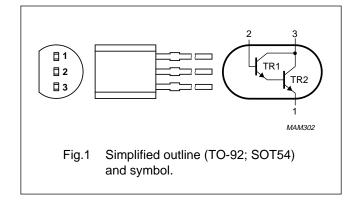
• Where very high amplification is required.

#### **DESCRIPTION**

NPN Darlington transistor in a TO-92; SOT54 plastic package. PNP complement: BC516.

#### **PINNING**

PIN	DESCRIPTION			
1	emitter			
2	base			
3	collector			



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS		TYP.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	_	_	40	V
V <sub>CES</sub>	collector-emitter voltage	V <sub>BE</sub> = 0	_	_	30	V
I <sub>C</sub>	collector current (DC)		_	_	500	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	_	_	500	mW
h <sub>FE</sub>	DC current gain	$I_C = 20 \text{ mA}; V_{CE} = 2 \text{ V}$	30000	_	_	
f <sub>T</sub>	transition frequency	$I_C = 30 \text{ mA}; V_{CE} = 5 \text{ V}; f = 100 \text{ MHz}$	_	220	_	MHz

## NPN Darlington transistor

BC517

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	PARAMETER CONDITIONS		MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	40	V
V <sub>CES</sub>	collector-emitter voltage	V <sub>BE</sub> = 0	_	30	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	10	V
I <sub>C</sub>	collector current (DC)		_	500	mA
I <sub>CM</sub>	peak collector current		_	800	mA
I <sub>B</sub>	base current (DC)		_	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	500	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	250	K/W

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

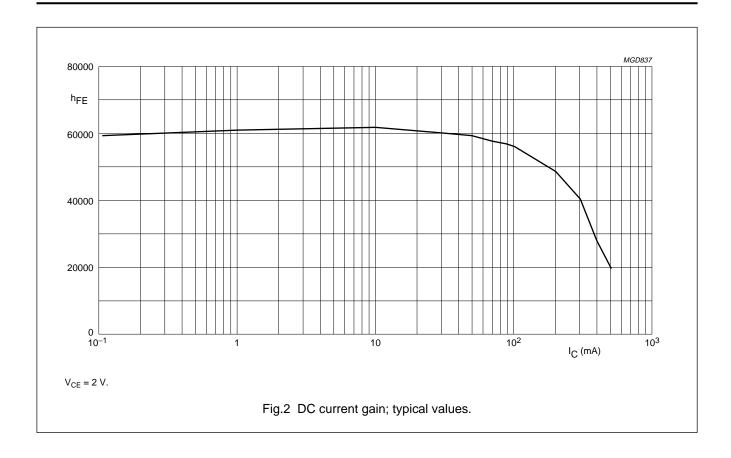
#### **CHARACTERISTICS**

 $T_j$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS			MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = 30 V	_	_	100	nA
I <sub>EBO</sub>	emitter cut-off current	I <sub>C</sub> = 0; V <sub>EB</sub> = 10 V	_	_	100	nA
h <sub>FE</sub>	DC current gain	$I_C = 20$ mA; $V_{CE} = 2$ V; see Fig.2	30000	_	_	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 100 \text{ mA}; I_B = 0.1 \text{ mA}$	_	_	1	V
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C = 100 \text{ mA}; I_B = 0.1 \text{ mA}$	_	_	1.5	V
V <sub>BEon</sub>	base-emitter on-state voltage	$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}$	_	_	1.4	V
f <sub>T</sub>	transition frequency	$I_C = 30 \text{ mA}; V_{CE} = 5 \text{ V}; f = 100 \text{ MHz}$	_	220	_	MHz

## NPN Darlington transistor

BC517



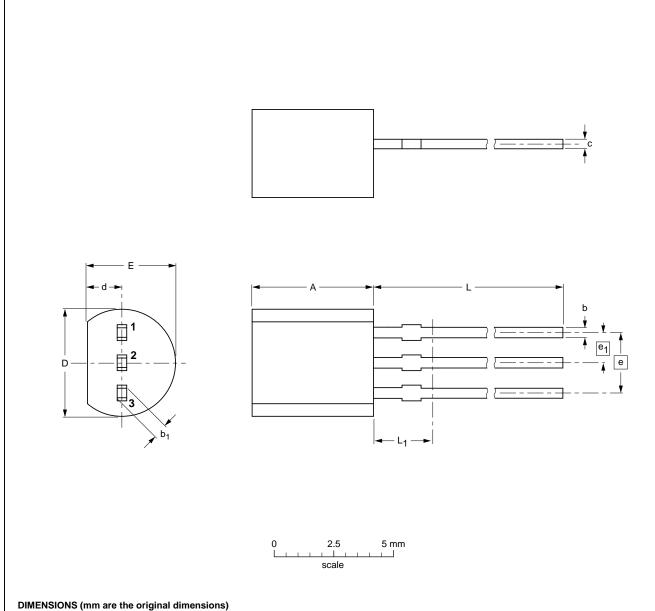
## NPN Darlington transistor

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#### **PACKAGE OUTLINE**

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



	•										
UNIT	Α	b	b <sub>1</sub>	С	D	d	E	е	e <sub>1</sub>	L	L <sub>1</sub> <sup>(1)</sup>
mm	5.2 5.0	0.48 0.40	0.66 0.56	0.45 0.40	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

#### Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFERENCES			EUROPEAN ISSUE DATE		I I I I I I I I I I I I I I I I I I I	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE		
SOT54		TO-92	SC-43			97-02-28		

#### NPN Darlington transistor

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#### **DEFINITIONS**

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

## NPN Darlington transistor

BC517

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Printed in The Netherlands

117047/00/03/pp8

Date of release: 1997 Apr 23

Document order number: 9397 750 02203

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